TPS564208 SOT-23パッケージ、4.5V～17V入力、4Aの同期整流降圧型電圧レギュレータ

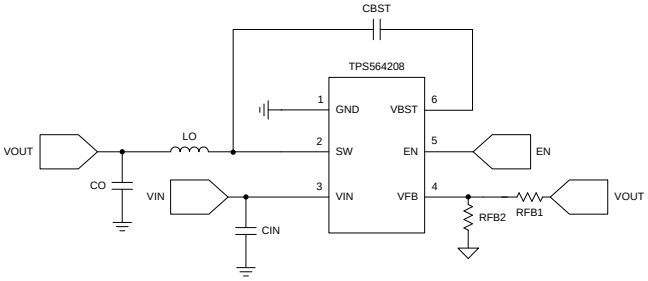
1 特長

- TPS564208: 50mΩおよび22mΩ FET内蔵の4Aコンバータ
- D-CAP2™モード制御による高速過渡応答
- 入力電圧範囲: 4.5V～17V
- 出力電圧範囲: 0.76V～7V
- 連続電流モード
- 560kHzのスイッチング周波数
- 低いシャットダウン電流: 10μA未満
- 帰還電圧精度: 1.6% (25℃)
- プリバイアス出力電圧からのスタートアップ
- サイクル単位の過電流制限
- Hiccupモードによる過電流保護
- 非ラッチUVPおよびTSD保護
- 固定ソフトスタート: 1.0ms
- WEBENCH® Power Designerにより、TPS564208を使用するカスタム設計を作成

2 アプリケーション

- デジタル・テレビ用電源
- 高精細 Blu-ray™ディスク・プレイヤー
- ネットワーク・ホーム・ターミナル
- デジタル・セットトップ・ボックス（STB）
- 監視機器

概略回路図



3 概要

TPS564208は単純で使いやすい、4A同期整流降圧型コンバータで、SOT-23パッケージに搭載されています。

このデバイスは最小の外付け部品数で動作し、スタンバイ電流が低くなるよう最適化されています。

これらのスイッチ・モード電源(SMPS)デバイスは、D-CAP2モード制御を採用し、高速の過渡応答を実現します。また、特殊ポリマーなどESR (等価直列抵抗)の低い出力コンデンサと、超低ESRのセラミック・コンデンサの両方を、外部補償部品なしでサポートします。

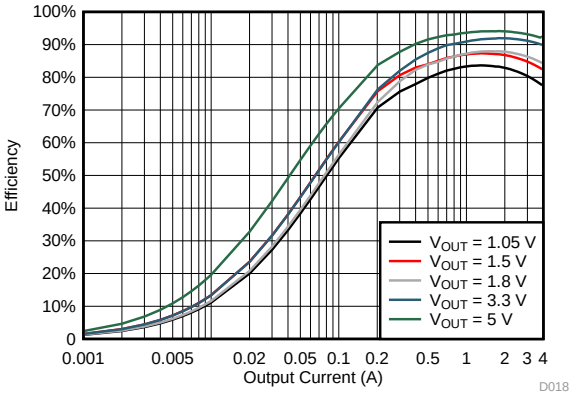
TPS564208は、6ピンの1.6mm×2.9mm SOT (DDC)パッケージで供給され、接合部温度-40℃～125℃で動作が規定されています。

製品情報(1)

型番	パッケージ	本体サイズ(公称)
TPS564208	DDC (6)	1.60mm×2.90mm

(1) 提供されているすべてのパッケージについては、このデータシートの末尾にある注文情報を参照してください。

TPS564208の効率



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4 改訂履歴

Revision A (October 2017) から **Revision B** に変更 **Page**

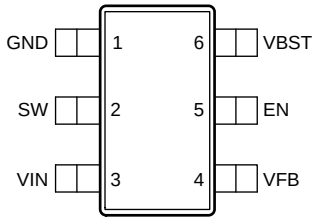
- Changed the I_{VIN} MAX value From: 780 µA To: 820 µA in the *Electrical Characteristics* ... 5

2016年3月発行のものから更新 **Page**

- 「特長」にWEBENCH® Designerへのリンクを 追加 ... 1
- Changed V_{FBTH} spec MIN from 739 to 745, TYP from 759 to 760, and MAX from 779 to 775 ... 5
- 追加 WEBENCH®ツールによるカスタム設計 ... 20

5 Pin Configuration and Functions

DDC Package
6-Pin SOT
Top View



Pin Functions

PIN		I/O	DESCRIPTION
NAME	NO.		
GND	1	—	Ground pin Source terminal of low-side power NFET as well as the ground terminal for controller circuit. Connect sensitive VFB to this GND at a single point.
SW	2	O	Switch node connection between high-side NFET and low-side NFET.
VIN	3	I	Input voltage supply pin. The drain terminal of high-side power NFET.
VFB	4	I	Converter feedback input. Connect to output voltage with feedback resistor divider.
EN	5	I	Enable input control. Active high and must be pulled up to enable the device.
VBST	6	O	Supply input for the high-side NFET gate drive circuit. Connect 0.1 µF capacitor between VBST and SW pins.

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
Input voltage	VIN, EN	–0.3	19	V
	VBST	–0.3	25	V
	VBST (10 ns transient)	–0.3	27	V
	VBST (vs SW)	–0.3	6.5	V
	VFB	–0.3	6.5	V
	SW	–2	19	V
	SW (10 ns transient)	–3.5	21	V
Operating junction temperature, T_J		–40	150	°C
Storage temperature, T_{stg}		–55	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±4000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101(2)	±1500	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	NOM	MAX	UNIT
V_{IN}	Supply input voltage range		4.5		17	V
V_I	Input voltage range	VBST	–0.1		23	V
		VBST (10 ns transient)	–0.1		26	
		VBST (vs SW)	–0.1		6.0	
		EN	–0.1		17	
		VFB	–0.1		5.5	
		SW	–1.8		17	
		SW (10 ns transient)	–3.5		20	
T_J	Operating junction temperature		–40		125	°C

6.4 Thermal Information

THERMAL METRIC(1)		TPS564208 DDC (SOT) 6 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	86.3	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	39.4	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	13.3	°C/W
ψ_{JT}	Junction-to-top characterization parameter	1.8	°C/W
ψ_{JB}	Junction-to-board characterization parameter	13.3	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

6.5 Electrical Characteristics

T_J = –40°C to 125°C, V_{IN} = 12 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY CURRENT						
I_{VIN}	Operating – non-switching supply current	V_{IN} current, EN = 5 V, V_{FB} = 1 V		640	820	µA
I_{VINSDN}	Shutdown supply current	V_{IN} current, EN = 0 V		0.9	5	µA
LOGIC THRESHOLD						
V_{ENH}	EN high-level input voltage	EN	1.6			V
V_{ENL}	EN low-level input voltage	EN			0.8	V
R_{EN}	EN pin resistance to GND	V_{EN} = 12 V	225	425	900	kΩ
V_{FB} VOLTAGE AND DISCHARGE RESISTANCE						
V_{FBTH}	V_{FB} threshold voltage	V_O = 1.05 V, continuous mode operation	745	760	775	mV
I_{VFB}	V_{FB} input current	V_{FB} = 0.8 V		0	±0.1	µA
MOSFET						
$R_{DS(on)h}$	High-side switch resistance	T_A = 25°C, V_{BST} – SW = 5.5 V		50		mΩ
$R_{DS(on)l}$	Low-side switch resistance	T_A = 25°C		22		mΩ
CURRENT LIMIT						
I_{ocl}	Current limit (1)	DC current, V_{OUT} = 1.05 V, L_1 = 1.5 µH	4.2	6	7.7	A
THERMAL SHUTDOWN						
T_{SDN}	Thermal shutdown threshold (1)	Shutdown temperature		172		°C
		Hysteresis		38		
ON-TIME TIMER CONTROL						
$t_{OFF(MIN)}$	Minimum off time	V_{FB} = 0.68 V		220	280	ns
SOFT START						
t_{SS}	Soft-start time	Internal soft-start time		1		ms
FREQUENCY						
F_{sw}	Switching frequency	V_{IN} = 12 V, V_O = 1.05 V, FCCM mode		560		kHz
OUTPUT UNDERVOLTAGE AND OVERVOLTAGE PROTECTION						
V_{UVP}	Output UVP threshold	Hiccup detect (H > L)		65%		
T_{HICCUP_WAIT}	Hiccup on time			1.9		ms
T_{HICCUP_RE}	Hiccup time before restart			15.5		ms
UVLO						
UVLO	UVLO threshold	Wake up VIN voltage		4	4.3	V
		Shutdown VIN voltage	3.3	3.6		
		Hysteresis VIN voltage (1)		0.4		

(1) Not production tested.

6.6 Typical Characteristics

V_{IN} = 12 V (unless otherwise noted)

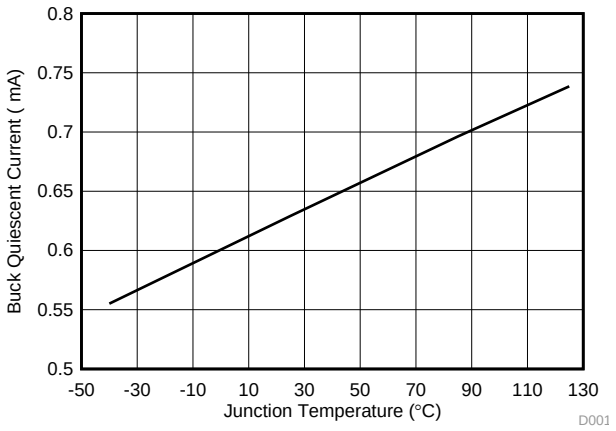


Figure 1. TPS564208 Supply Current vs Junction Temperature

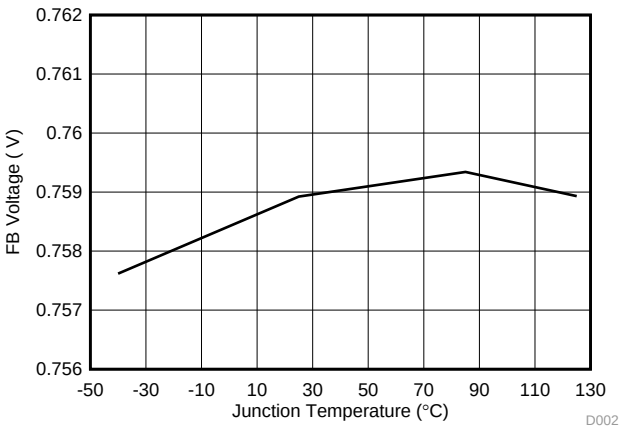


Figure 2. VFB Voltage vs Junction Temperature

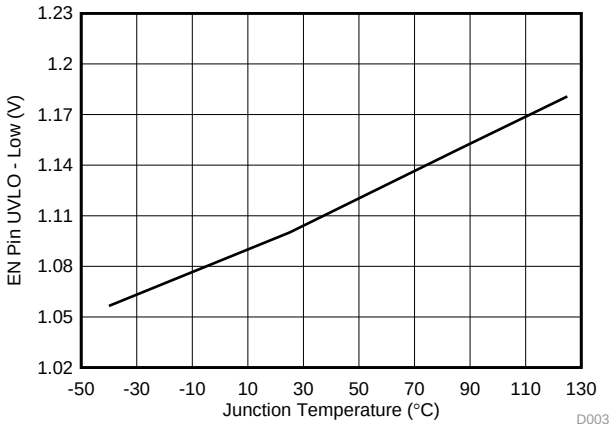


Figure 3. EN Pin UVLO Low Voltage vs Junction Temperature

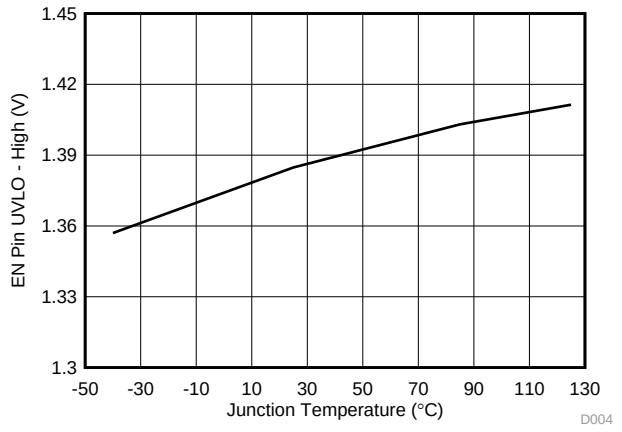


Figure 4. TPS564208 EN Pin UVLO High Voltage vs Junction Temperature

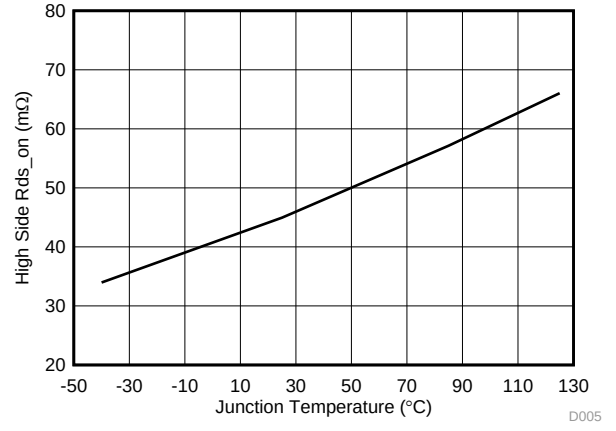


Figure 5. High-Side $R_{ds\text{-}On}$ vs Junction Temperature

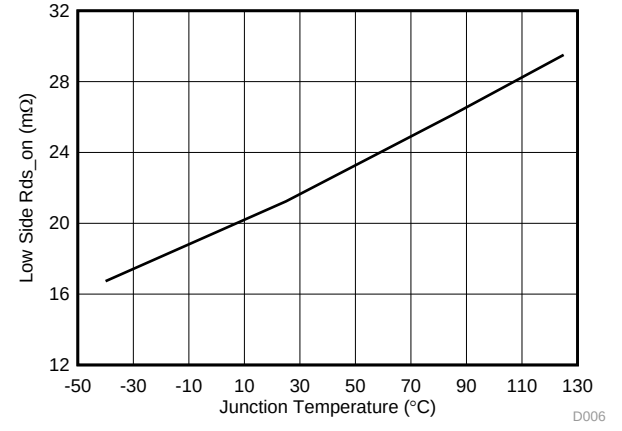
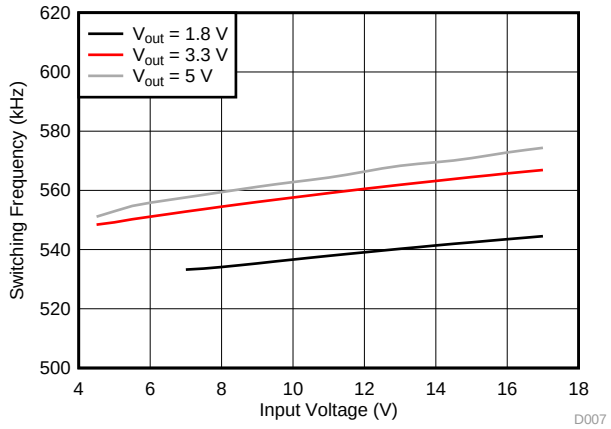


Figure 6. Low-Side $R_{ds\text{-}On}$ vs Junction Temperature

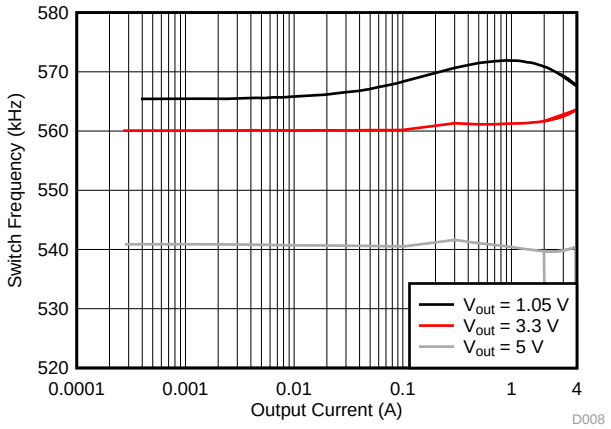
Typical Characteristics (continued)

V_{IN} = 12 V (unless otherwise noted)



I_{OUT} = 1 A

Figure 7. TPS564208 Switching Frequency vs Input Voltage



V_{IN} = 12 V

Figure 8. TPS564208 Switching Frequency vs Output Current

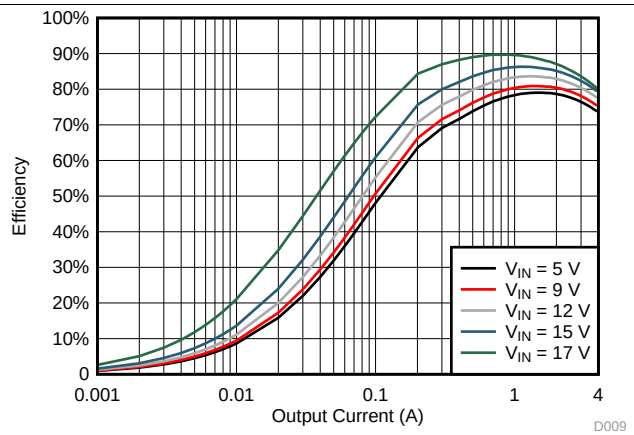


Figure 9. TPS564208 V_{OUT} = 1.05 V Efficiency, L = 2.2 µH

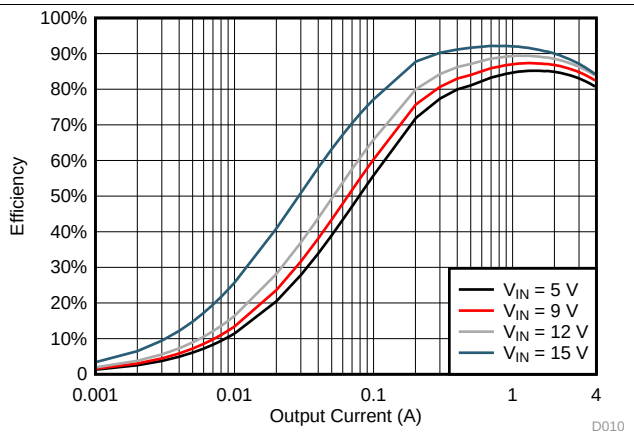


Figure 10. TPS564208 V_{OUT} = 1.5 V Efficiency, L = 2.2 µH

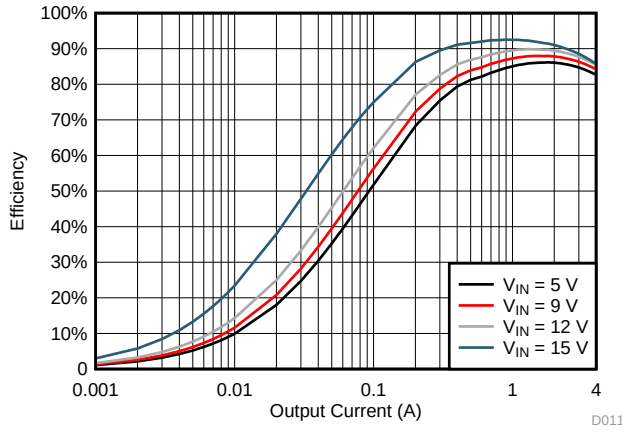


Figure 11. TPS564208 V_{OUT} = 1.8 V Efficiency, L = 2.2 µH

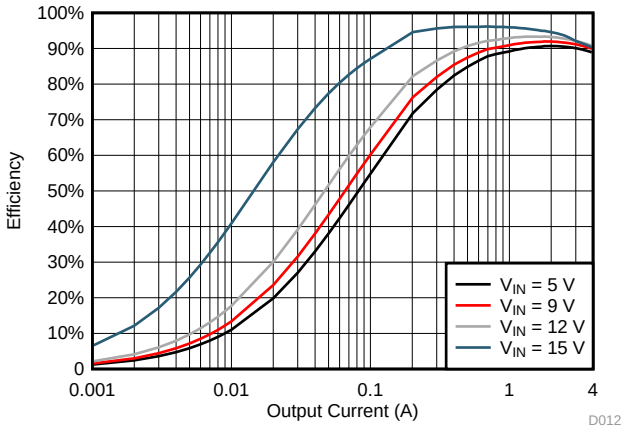


Figure 12. TPS564208 V_{OUT} = 3.3 V Efficiency, L = 2.2 µH

Typical Characteristics (continued)

V_{IN} = 12 V (unless otherwise noted)

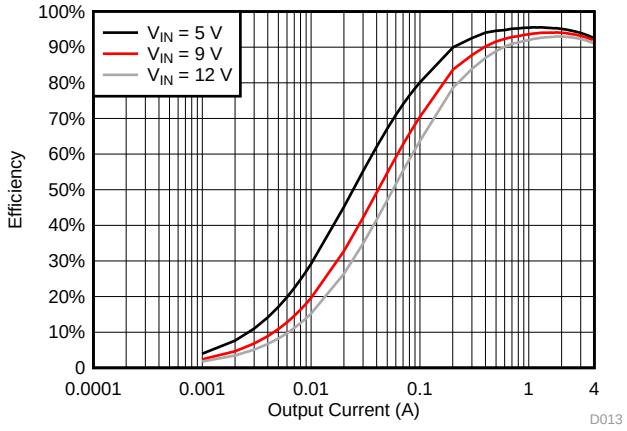


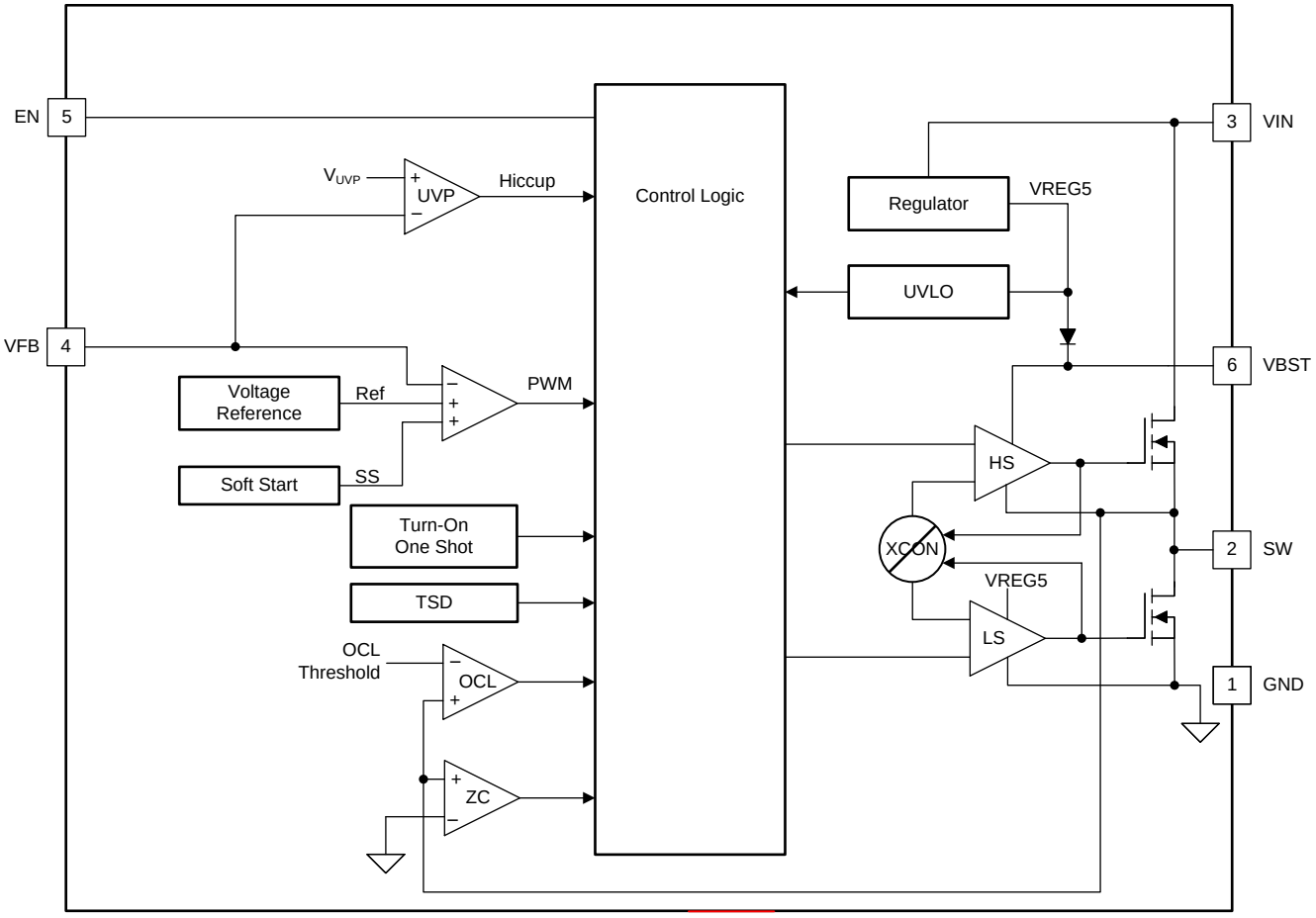
Figure 13. TPS564208 V_{OUT} = 5 V Efficiency, L = 3.3 µH

7 Detailed Description

7.1 Overview

The TPS564208 is a 4-A synchronous step-down converter. The proprietary D-CAP2™ mode control supports low ESR output capacitors such as specialty polymer capacitors and multi-layer ceramic capacitors without complex external compensation circuits. The fast transient response of D-CAP2™ mode control can reduce the output capacitance required to meet a specific level of performance.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Adaptive On-Time Control and PWM Operation

The main control loop of the TPS564208 is adaptive on-time pulse width modulation (PWM) controller that supports a proprietary D-CAP2™ mode control. The D-CAP2™ mode control combines adaptive on-time control with an internal compensation circuit for pseudo-fixed frequency and low external component count configuration with both low-ESR and ceramic output capacitors. It is stable even with virtually no ripple at the output.

At the beginning of each cycle, the high-side MOSFET is turned on. This MOSFET is turned off after internal one-shot timer expires. This one shot duration is set inversely proportional to the converter input voltage, V_{IN}, and proportional to the output voltage V_O, to maintain a pseudo-fixed frequency over the input voltage range, hence it is called adaptive on-time control. The one-shot timer is reset and the high-side MOSFET is turned on again when the feedback voltage falls below the reference voltage. An internal ramp is added to reference voltage to simulate output ripple, eliminating the need for ESR induced output ripple from D-CAP2™ mode control.

7.3.2 Soft Start and Pre-Biased Soft Start

The TPS564208 has an internal 1.0-ms soft-start. When the EN pin becomes high, the internal soft-start function begins ramping up the reference voltage to the PWM comparator.

If the output capacitor is pre-biased at startup, the device initiates switching and starts ramping up only after the internal reference voltage becomes greater than the feedback voltage V_{FB}. This scheme ensures that the converter ramps up smoothly into regulation point.

Feature Description (continued)

7.3.3 Current Protection

The output over-current limit (OCL) is implemented using a cycle-by-cycle valley detect control circuit. The switch current is monitored during the OFF state by measuring the low-side FET drain to source voltage. This voltage is proportional to the switch current. To improve accuracy, the voltage sensing is temperature compensated.

During the on time of the high-side FET switch, the switch current increases at a linear rate determined by V_{IN}, V_{OUT}, the on-time and the output inductor value. During the on time of the low-side FET switch, this current decreases linearly. The average value of the switch current is the load current Iout. If the monitored current is above the OCL level, the converter maintains low-side FET on and delays the creation of a new set pulse, even the voltage feedback loop requires one, until the current level becomes OCL level or lower. In subsequent switching cycles, the on-time is set to a fixed value and the current is monitored in the same manner.

There are some important considerations for this type of over-current protection. The load current is higher than the over-current threshold by one half of the peak-to-peak inductor ripple current. Also, when the current is being limited, the output voltage tends to fall as the demanded load current may be higher than the current available from the converter. This may cause the output voltage to fall. When the VFB voltage falls below the UVP threshold voltage, the UVP comparator detects it. And then, the device shuts down after the UVP delay time (typically 24 µs) and re-starts after the hiccup time (typically 15.5 ms).

When the over current condition is removed, the output voltage returns to the regulated value.

7.3.4 Undervoltage Lockout (UVLO) Protection

UVLO protection monitors the internal regulator voltage. When the voltage is lower than UVLO threshold voltage, the device is shut off. This protection is non-latching.

7.3.5 Thermal Shutdown

The device monitors the temperature of itself. If the temperature exceeds the threshold value (typically 172°C), the device is shut off. This is a non-latch protection.

7.4 Device Functional Modes

7.4.1 Normal Operation

When the input voltage is above the UVLO threshold and the EN voltage is above the enable threshold, the TPS564208 operates in the normal switching mode. Normal continuous conduction mode (CCM) occurs when the minimum switch current is above 0 A. In CCM, the TPS564208 operates at a quasi-fixed frequency of 560 kHz.

7.4.2 Standby Operation

When the TPS564208 is operating in normal CCM, it may be placed in standby by asserting the EN pin low.

8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The device is a typical step-down DC-DC converter for converting a higher dc voltage to a lower dc voltage with a maximum available output current of 4 A. The following design procedure can be used to select component values for the TPS564208. Alternately, the WEBENCH® software may be used to generate a complete design. The WEBENCH software uses an iterative design procedure and accesses a comprehensive database of components when generating a design. This section presents a simplified discussion of the design process.

8.2 Typical Application

The application schematic in Figure 14 shows the TPS564208 4.5-V to 17-V input, 1.05-V output converter design meeting the requirements for 4-A output. This circuit is available as the evaluation module (EVM). The sections provide the design procedure.

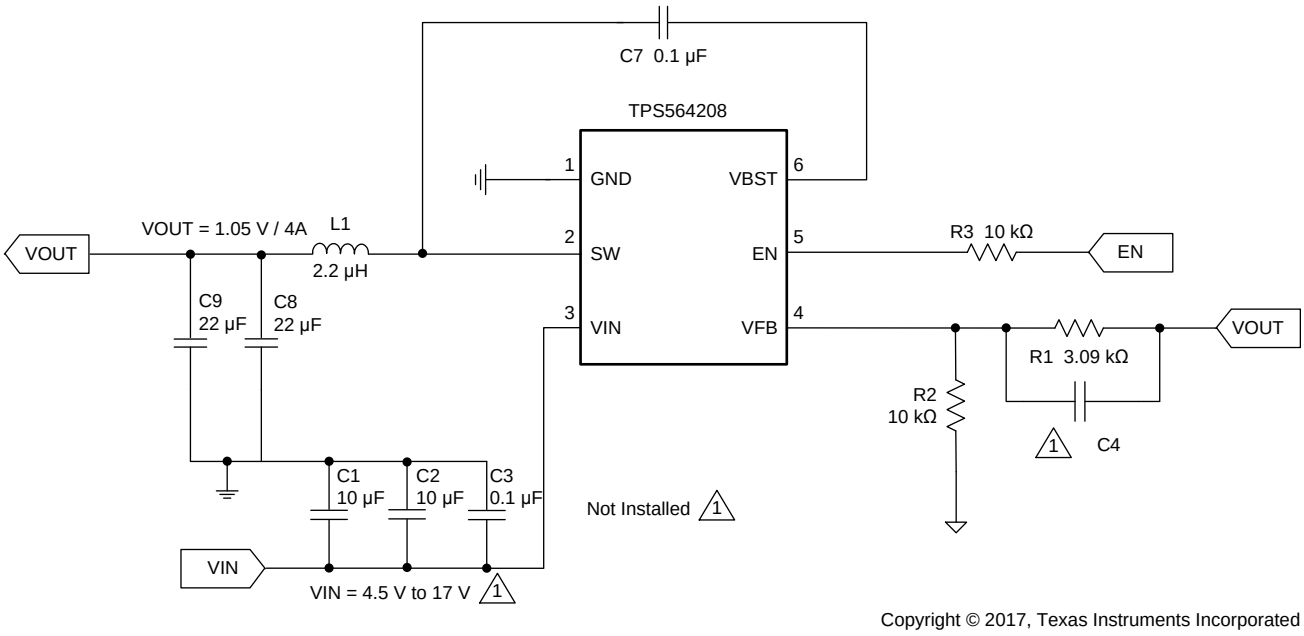


Figure 14. TPS564208 1.05-V, 4-A Reference Design

Typical Application (continued)

8.2.1 Design Requirements

Table 1 shows the design parameters for this application.

Table 1. Design Parameters

PARAMETER	EXAMPLE VALUE
Input voltage range	4.5 to 17 V
Output voltage	1.05 V
Transient response, 2-A load step	ΔVout = ±5%
Input ripple voltage	400 mV
Output ripple voltage	30 mV
Output current rating	4 A
Operating frequency	560 kHz

8.2.2 Detailed Design Procedure

8.2.2.1 Custom Design With WEBENCH® Tools

Click here to create a custom design using the TPS564208 device with the WEBENCH® Power Designer.

1. Start by entering the input voltage (V_{IN}), output voltage (V_{OUT}), and output current (I_{OUT}) requirements.
2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at www.ti.com/WEBENCH.

8.2.2.2 Output Voltage Resistors Selection

The output voltage is set with a resistor divider from the output node to the VFB pin. TI recommends to use 1% tolerance or better divider resistors. Start by using to calculate V_{OUT}.

To improve efficiency at very light loads consider using larger value resistors. However, using too high of resistance causes the circuit to be more susceptible to noise; and, voltage errors from the VFB input current will be more noticeable.

$$V_{OUT} = 0.760 \times \left(1 + \frac{R1}{R2}\right) \quad (1)$$

8.2.2.3 Output Filter Selection

The LC filter used as the output filter has double pole at:

$$f_P = \frac{1}{2\pi\sqrt{L_{OUT} \times C_{OUT}}} \quad (2)$$

At low frequencies, the overall loop gain is set by the output set-point resistor divider network and the internal gain of the device. The low frequency phase is 180°. At the output filter pole frequency, the gain rolls off at a –40 dB per decade rate and the phase drops rapidly. D-CAP2 introduces a high frequency zero that reduces the gain roll off to –20 dB per decade and increases the phase to 90° one decade above the zero frequency. The inductor and capacitor for the output filter must be selected so that the double pole of Equation 2 is located below the high frequency zero but close enough that the phase boost provided be the high frequency zero provides adequate phase margin for a stable circuit. To meet this requirement use the values recommended in Table 2.

Table 2. Recommended Component Values

OUTPUT VOLTAGE (V)	R1 (kΩ)	R2 (kΩ)	L1 (µH)			C8 + C9 (µF)
			MIN	TYP	MAX	
1	3.09	10.0	1.5	2.2	4.7	20 to 68
1.05	3.74	10.0	1.5	2.2	4.7	20 to 68
1.2	5.76	10.0	1.5	2.2	4.7	20 to 68
1.5	9.53	10.0	1.5	2.2	4.7	20 to 68
1.8	13.7	10.0	1.5	2.2	4.7	20 to 68
2.5	22.6	10.0	2.2	2.2	4.7	20 to 68
3.3	33.2	10.0	2.2	2.2	4.7	20 to 68
5	54.9	10.0	3.3	3.3	4.7	20 to 68
6.5	75	10.0	3.3	3.3	4.7	20 to 68

The inductor peak-to-peak ripple current, peak current and RMS current are calculated using Equation 3, Equation 4, and Equation 5. The inductor saturation current rating must be greater than the calculated peak current and the RMS or heating current rating must be greater than the calculated RMS current.

Use 560 kHz for f_{SW}. Make sure the chosen inductor is rated for the peak current of Equation 4 and the RMS current of Equation 6.

$$I_{P-P} = \frac{V_{OUT}}{V_{IN(MAX)}} \times \frac{V_{IN(MAX)} - V_{OUT}}{L_O \times f_{SW}} \quad (3)$$

$$I_{PEAK} = I_O + \frac{I_{P-P}}{2} \quad (4)$$

$$I_{LO(RMS)} = \sqrt{I_O^2 + \frac{1}{12} I_{P-P}^2} \quad (5)$$

For this design example, the calculated peak current is 4.4 A and the calculated RMS current is 4 A. The inductor used is a WE 74431122 with a peak current rating of 13 A and an RMS current rating of 9 A.

The capacitor value and ESR determines the amount of output voltage ripple. The TPS564208 is intended for use with ceramic or other low ESR capacitors. Recommended values range from 20 µF to 68 µF. Use Equation 6 to determine the required RMS current rating for the output capacitor.

$$I_{CO(RMS)} = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{\sqrt{12} \times V_{IN} \times L_O \times f_{SW}} \quad (6)$$

For this design two TDK C3216X5R0J226M 22-µF output capacitors are used. The typical ESR is 2 mΩ each. The calculated RMS current is 0.286 A and each output capacitor is rated for 4 A.

8.2.2.4 Input Capacitor Selection

The TPS564208 requires an input decoupling capacitor and a bulk capacitor is needed depending on the application. TI recommends a ceramic capacitor over 10 µF for the decoupling capacitor. An additional 0.1-µF capacitor (C3) from pin 3 to ground is optional to provide additional high frequency filtering. The capacitor voltage rating needs to be greater than the maximum input voltage.

8.2.2.5 Bootstrap Capacitor Selection

A 0.1-µF ceramic capacitor must be connected between the VBST to SW pin for proper operation. TI recommends to use a ceramic capacitor.

8.2.3 Application Curves

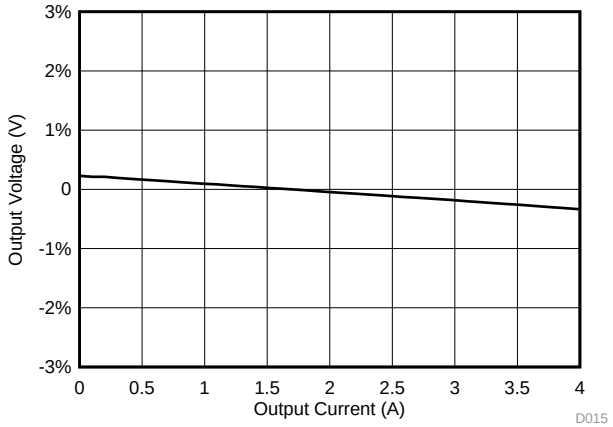


Figure 15. TPS564208 Load Regulation, V_{IN} = 5 V

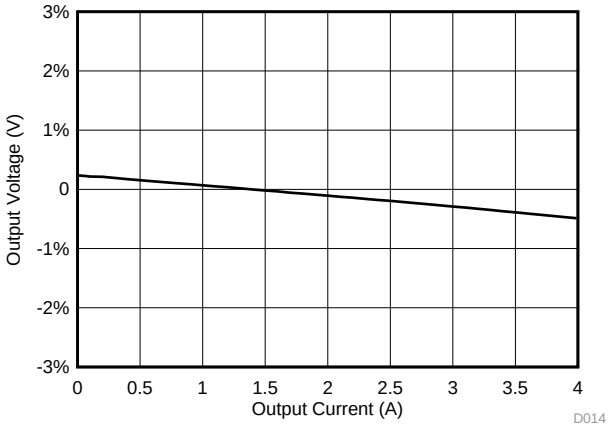


Figure 16. TPS564208 Load Regulation, V_{IN} = 12 V

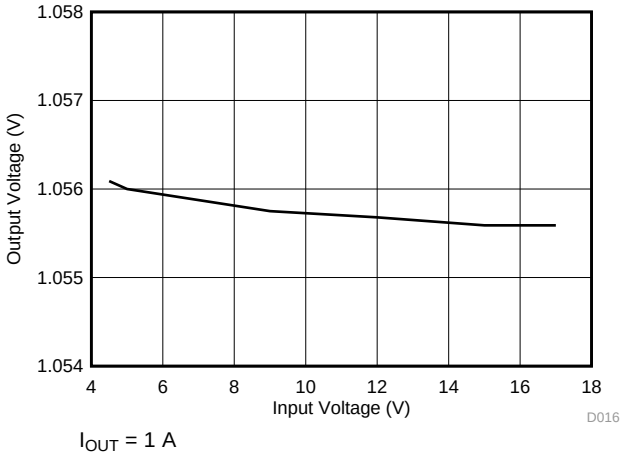


Figure 17. TPS564208 Line Regulation

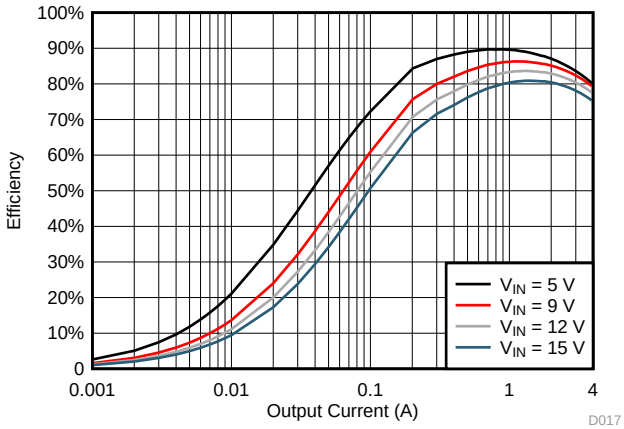


Figure 18. TPS564208 Efficiency, V_{out} = 1.05 V

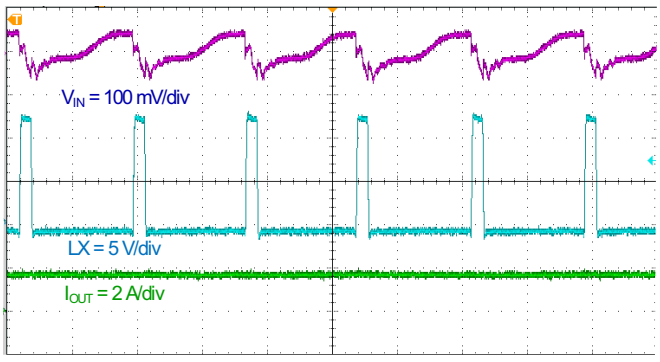


Figure 19. TPS564208 Input Voltage Ripple

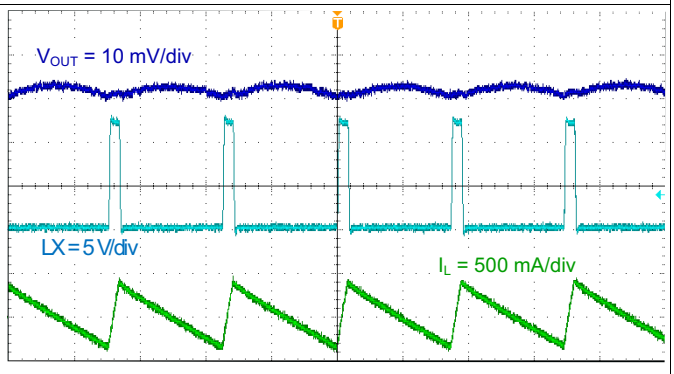
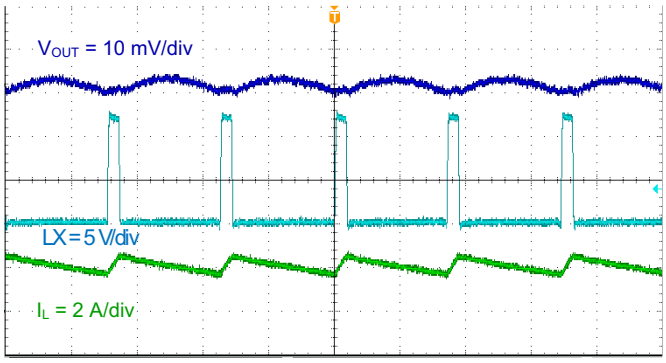
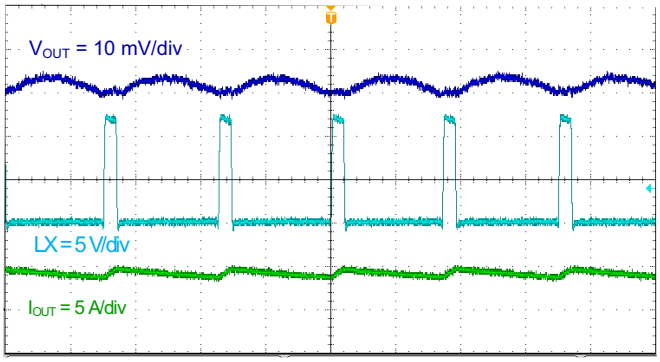


Figure 20. TPS564208 Output Voltage Ripple, No Load



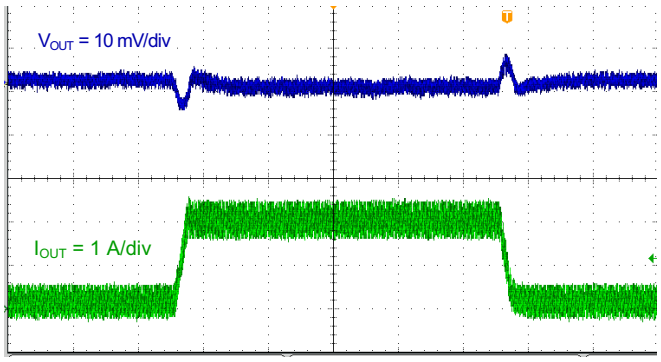
1 µs/div

Figure 21. TPS564208 Output Voltage Ripple, I_{OUT} 2 A



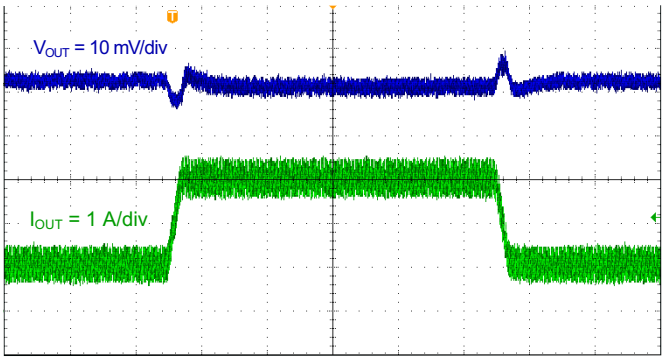
1 µs/div

Figure 22. TPS564208 Output Voltage Ripple, I_{OUT} 4 A



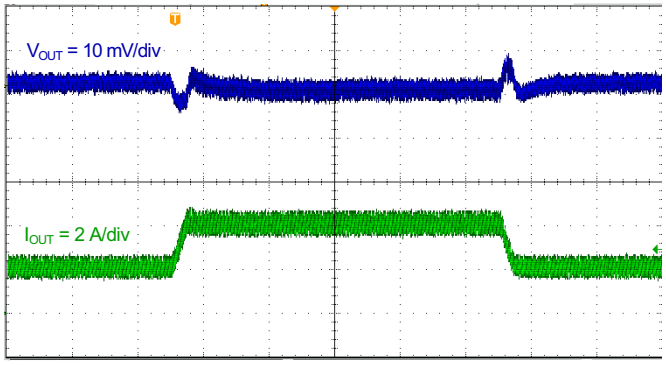
100 µs/div

Figure 23. TPS564208 Transient Response 0.1 to 2 A



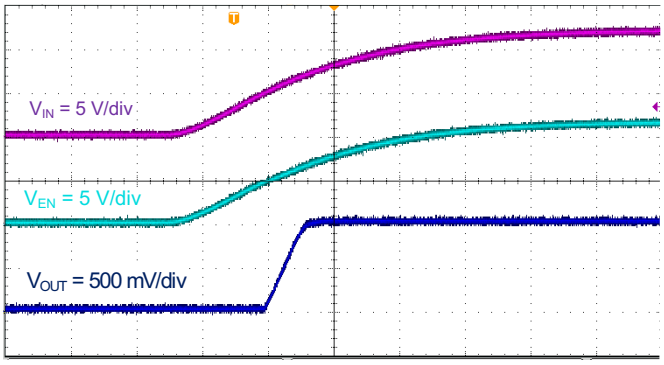
100 µs/div

Figure 24. TPS564208 Transient Response, 1 to 3 A



100 µs/div

Figure 25. TPS564208 Transient Response, 2 to 4 A



2 ms/div

Figure 26. TPS564208 Startup Relative to V_{IN}

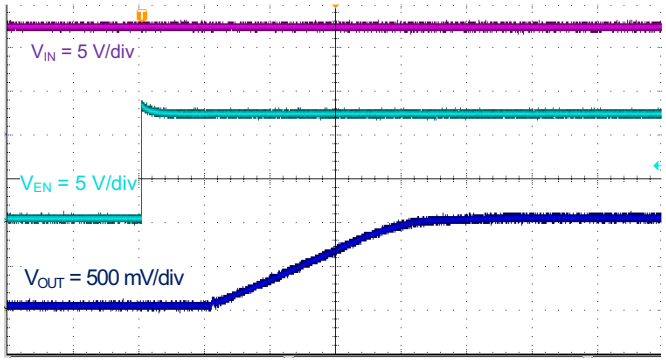


Figure 27. TPS564208 Startup Relative to EN

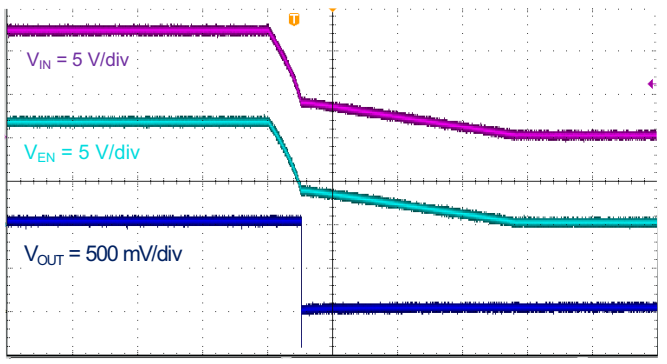


Figure 28. TPS564208 Shutdown Relative to V_{IN}

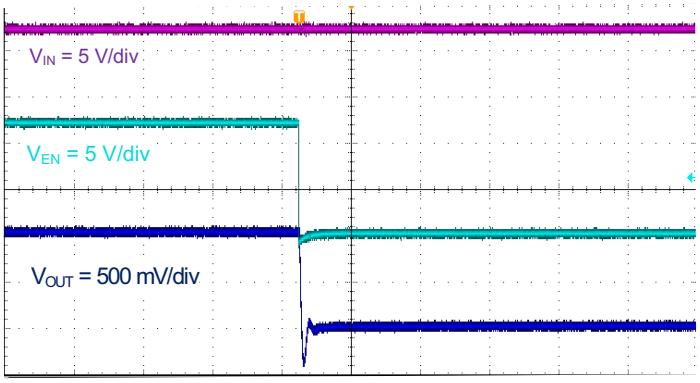


Figure 29. TPS564208 Shutdown Relative to EN

9 Power Supply Recommendations

The TPS564208 is designed to operate from input supply voltage in the range of 4.5 V to 17 V. Buck converters require the input voltage to be higher than the output voltage for proper operation. The maximum recommended operating duty cycle is 75%. Using that criteria, the minimum recommended input voltage is V_O / 0.75.

10 Layout

10.1 Layout Guidelines

1. VIN and GND traces should be as wide as possible to reduce trace impedance. The wide areas are also of advantage from the view point of heat dissipation.
2. The input capacitor and output capacitor should be placed as close to the device as possible to minimize trace impedance.
3. Provide sufficient vias for the input capacitor and output capacitor.
4. Keep the SW trace as physically short and wide as practical to minimize radiated emissions.
5. Do not allow switching current to flow under the device.
6. A separate VOUT path should be connected to the upper feedback resistor.
7. Make a Kelvin connection to the GND pin for the feedback path.
8. Voltage feedback loop should be placed away from the high-voltage switching trace, and preferably has ground shield.
9. The trace of the VFB node should be as small as possible to avoid noise coupling.
10. The GND trace between the output capacitor and the GND pin should be as wide as possible to minimize its trace impedance.

10.2 Layout Example

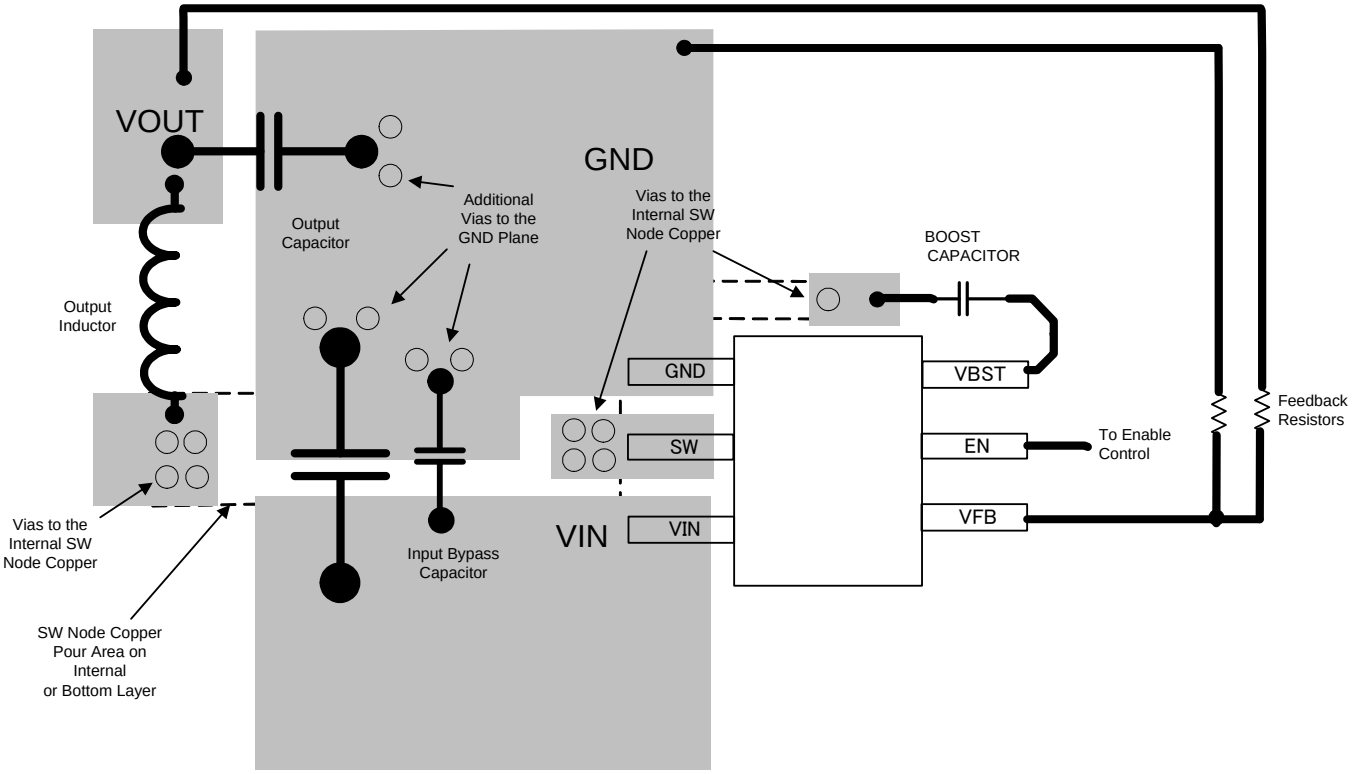


Figure 30. TPS564208 Layout Example

11 デバイスおよびドキュメントのサポート

11.1 開発サポート

11.1.1 WEBENCH®ツールによるカスタム設計

ここをクリックすると、WEBENCH® Power Designerにより、TPS564208デバイスを使用するカスタム設計を作成できます。

1. 最初に、入力電圧(V_{IN})、出力電圧(V_{OUT})、出力電流(I_{OUT})の要件を入力します。
2. オプティマイザのダイヤルを使用して、効率、占有面積、コストなどの主要なパラメータについて設計を最適化します。
3. 生成された設計を、テキサス・インスツルメンツが提供する他のソリューションと比較します。

WEBENCH Power Designerでは、カスタマイズされた回路図と部品リストを、リアルタイムの価格と部品の在庫情報と併せて参照できます。

ほとんどの場合、次の操作を実行可能です。

- 電気的なシミュレーションを実行し、重要な波形と回路の性能を確認する。
- 熱シミュレーションを実行し、基板の熱特性を把握する。
- カスタマイズされた回路図やレイアウトを、一般的なCADフォーマットでエクスポートする。
- 設計のレポートをPDFで印刷し、同僚と設計を共有する。

WEBENCHツールの詳細は、www.ti.com/WEBENCHでご覧になれます。

11.2 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、ti.comのデバイス製品フォルダを開いてください。右上の隅にある「*通知を受け取る*」をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取れます。変更の詳細については、修正されたドキュメントに含まれている改訂履歴をご覧ください。

11.3 コミュニティ・リソース

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

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設計サポート ***TIの設計サポート*** **役に立つE2Eフォーラムや、設計サポート・ツールをすばやく見つけることができます。技術サポート用の連絡先情報も参照できます。**

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WEBENCH is a registered trademark of Texas Instruments.
Blu-ray is a trademark of Blu-ray Disc Association.
All other trademarks are the property of their respective owners.

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11.6 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 メカニカル、パッケージ、および注文情報

以降のページには、メカニカル、パッケージ、および注文に関する情報が記載されています。この情報は、そのデバイスについて利用可能な最新のデータです。このデータは予告なく変更されることがあり、ドキュメントが改訂される場合もあります。本データシートのブラウザ版を使用されている場合は、画面左側の説明をご覧ください。

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS564208DDCR	ACTIVE	SOT-23-THIN	DDC	6	3000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	4208	Samples
TPS564208DDCT	ACTIVE	SOT-23-THIN	DDC	6	250	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	4208	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

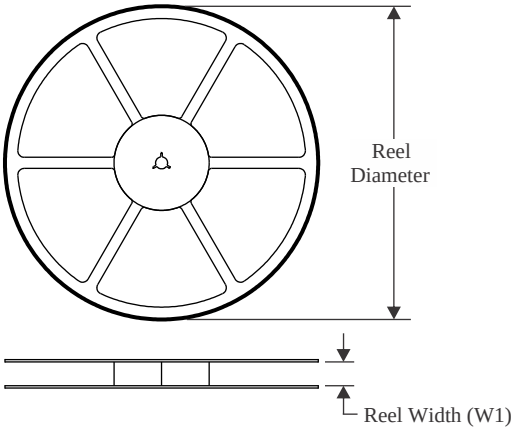
(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

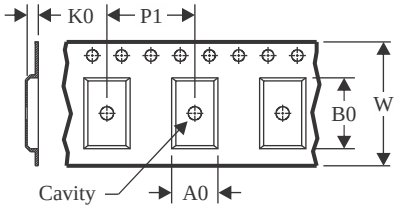
(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

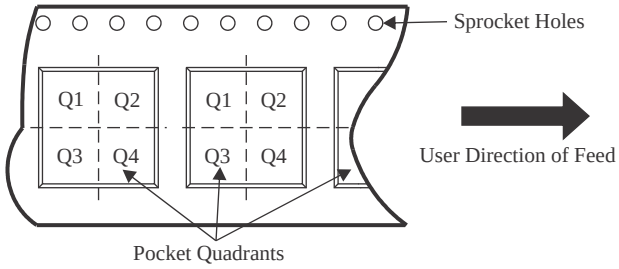


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

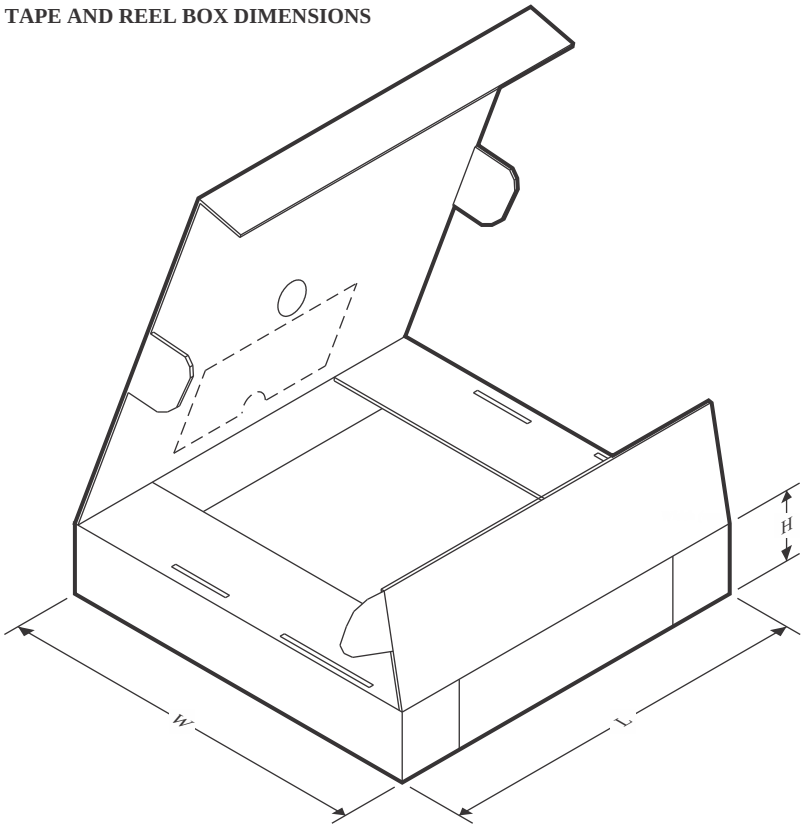
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS564208DDCR	SOT-23-THIN	DDC	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS564208DDCT	SOT-23-THIN	DDC	6	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

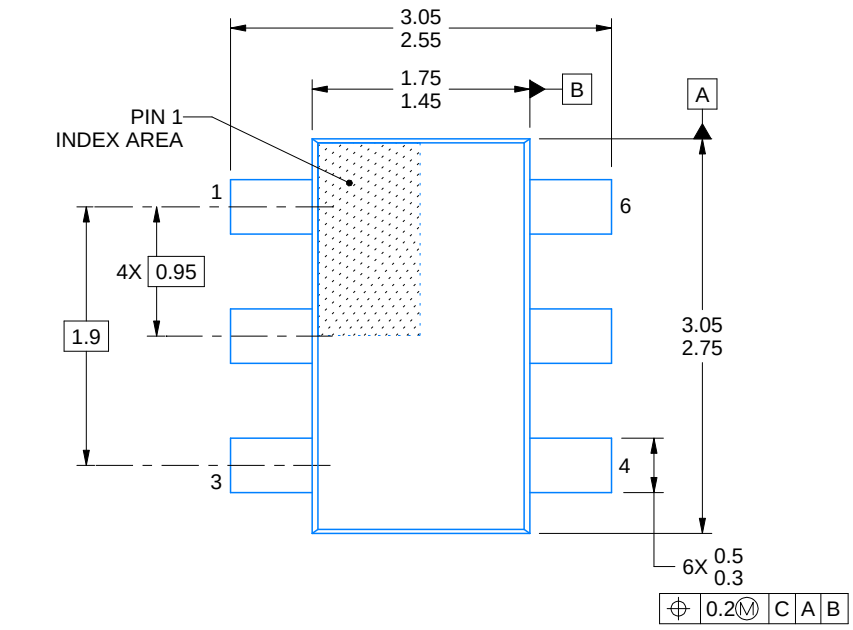
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS564208DDCR	SOT-23-THIN	DDC	6	3000	210.0	185.0	35.0
TPS564208DDCT	SOT-23-THIN	DDC	6	250	210.0	185.0	35.0

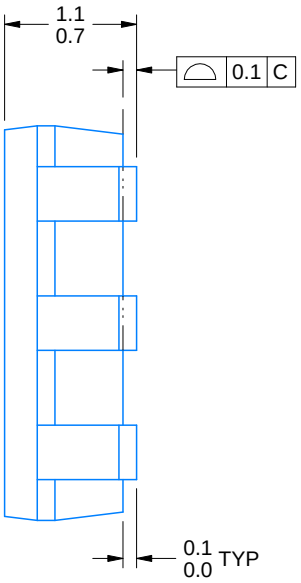
PACKAGE OUTLINE

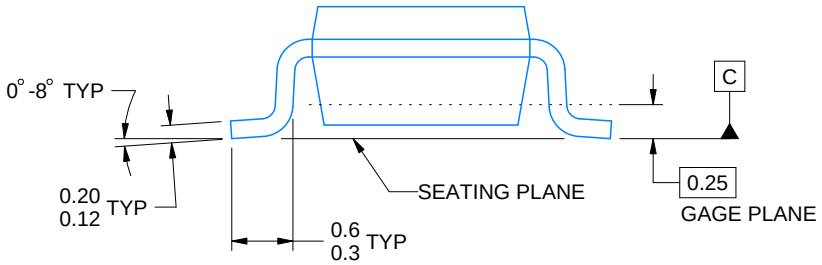
DDC0006A

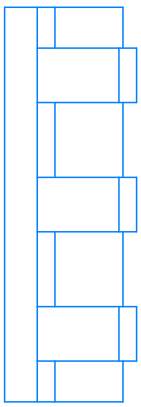
SOT-23 - 1.1 max height

SMALL OUTLINE TRANSISTOR







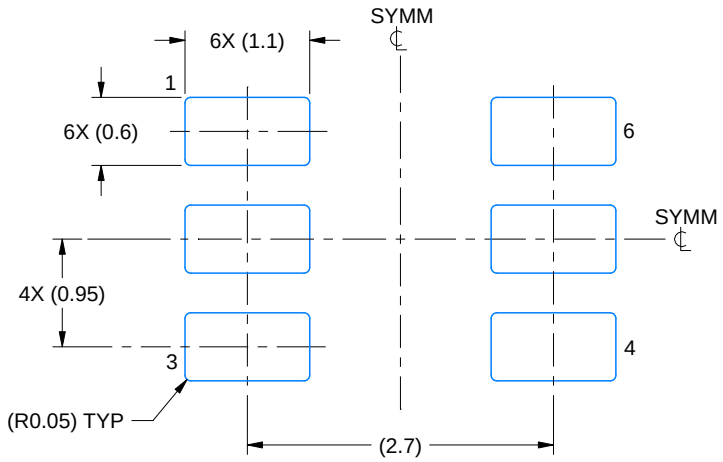


ALTERNATIVE PACKAGE
SINGULATION VIEW

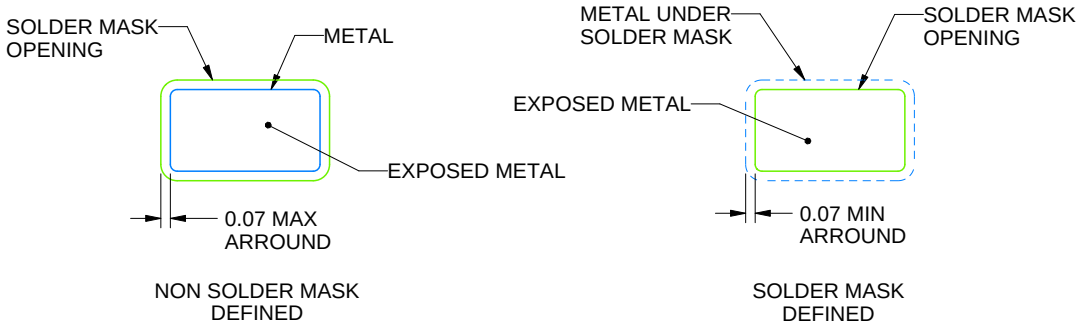
4214841/D 06/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-193.



LAND PATTERN EXAMPLE
EXPLOSED METAL SHOWN
SCALE:15X

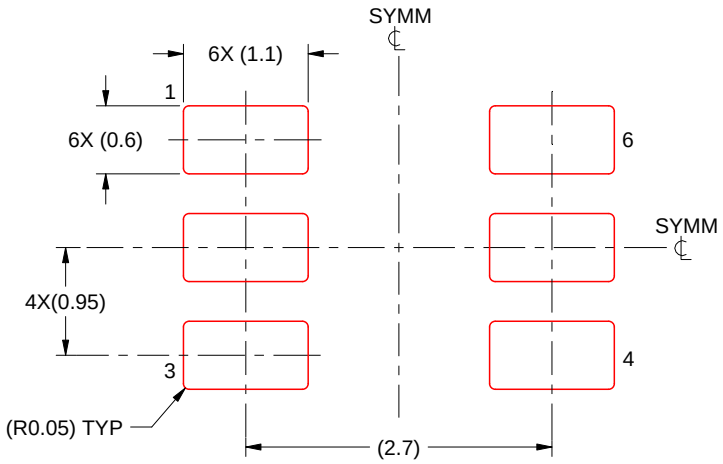


SOLDERMASK DETAILS

4214841/D 06/2024

NOTES: (continued)

4. Publication IPC-7351 may have alternate designs.
5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:15X

4214841/D 06/2024

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
7. Board assembly site may have different recommendations for stencil design.

重要なお知らせと免責事項

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